1 Product profile

1.1 General description
PNP general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>NPN complement</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Nexperia</td>
<td>JEDEC</td>
</tr>
<tr>
<td>BC807K-16</td>
<td>SOT23</td>
<td>TO-236AB</td>
</tr>
<tr>
<td>BC807K-25</td>
<td></td>
<td></td>
</tr>
<tr>
<td>BC807K-40</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

1.2 Features and benefits
- Three current gain selections
- High power dissipation capability
- AEC-Q101 qualified

1.3 Applications
- General-purpose switching and amplification
### 1.4 Quick reference data

Table 2. Quick reference data

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>(V_{CEO})</td>
<td>collector-emitter voltage</td>
<td>open base</td>
<td>-</td>
<td>-</td>
<td>-45</td>
<td>V</td>
</tr>
<tr>
<td>(I_C)</td>
<td>collector current</td>
<td>-</td>
<td>-</td>
<td>-</td>
<td>-500</td>
<td>mA</td>
</tr>
<tr>
<td>(I_{CM})</td>
<td>peak collector current</td>
<td>single pulse; (t_p \leq 1) ms</td>
<td>-</td>
<td>-</td>
<td>-1</td>
<td>A</td>
</tr>
<tr>
<td>(h_{FE})</td>
<td>DC current gain</td>
<td>(V_{CE} = -1) V; (I_C = -100) mA</td>
<td>[1] 100</td>
<td>-</td>
<td>250</td>
<td>-</td>
</tr>
<tr>
<td></td>
<td>BC807K-16</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>BC807K-25</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>BC807K-40</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

[1] pulsed; \(t_p \leq 300\) μs; \(\delta \leq 0.02\)

### 2 Pinning information

Table 3. Pinning

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>B</td>
<td>base</td>
<td><img src="image" alt="Simplified outline" /></td>
<td><img src="image" alt="Graphic symbol" /></td>
</tr>
<tr>
<td>2</td>
<td>E</td>
<td>emitter</td>
<td></td>
<td></td>
</tr>
<tr>
<td>3</td>
<td>C</td>
<td>collector</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

![Simplified outline](image)

![Graphic symbol](image)

### 3 Ordering information

Table 4. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Name</th>
<th>Description</th>
<th>Version</th>
</tr>
</thead>
<tbody>
<tr>
<td>BC807K-16</td>
<td>TO-236AB</td>
<td>Plastic surface-mounted package; 3 leads</td>
<td>SOT23</td>
<td></td>
</tr>
<tr>
<td>BC807K-25</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BC807K-40</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
4 Marking

Table 5. Marking

<table>
<thead>
<tr>
<th>Type number</th>
<th>Marking code</th>
</tr>
</thead>
<tbody>
<tr>
<td>BC807K-16</td>
<td>[1] HA%</td>
</tr>
<tr>
<td>BC807K-25</td>
<td>[1] HB%</td>
</tr>
<tr>
<td>BC807K-40</td>
<td>[1] HC%</td>
</tr>
</tbody>
</table>

[1] % = placeholder for manufacturing site code

5 Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_CBO</td>
<td>collector-base voltage</td>
<td>open emitter</td>
<td>-</td>
<td>-50</td>
<td>V</td>
</tr>
<tr>
<td>V_CEO</td>
<td>collector-emitter voltage</td>
<td>open base</td>
<td>-</td>
<td>-45</td>
<td>V</td>
</tr>
<tr>
<td>V_EBO</td>
<td>emitter-base voltage</td>
<td>open collector</td>
<td>-</td>
<td>-5</td>
<td>V</td>
</tr>
<tr>
<td>I_C</td>
<td>collector current</td>
<td></td>
<td>-</td>
<td>-500</td>
<td>mA</td>
</tr>
<tr>
<td>I_CM</td>
<td>peak collector current</td>
<td>single pulse; ( t_p \leq 1 \text{ ms} )</td>
<td>-</td>
<td>-1</td>
<td>A</td>
</tr>
<tr>
<td>I_BM</td>
<td>peak base current</td>
<td>single pulse; ( t_p \leq 1 \text{ ms} )</td>
<td>-</td>
<td>-200</td>
<td>mA</td>
</tr>
<tr>
<td>P_tot</td>
<td>total power dissipation</td>
<td>( T_{\text{amb}} \leq 25 \degree \text{C} )</td>
<td>[1]</td>
<td>350</td>
<td>mW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>[2]</td>
<td></td>
<td>575</td>
<td>mW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>[3]</td>
<td></td>
<td>600</td>
<td>mW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>[4]</td>
<td></td>
<td>800</td>
<td>mW</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Condition</th>
<th>Value 1</th>
<th>Value 2</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>T_j</td>
<td>junction temperature</td>
<td>-</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>T_amb</td>
<td>ambient temperature</td>
<td>55</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>T_stg</td>
<td>storage temperature</td>
<td>-65</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm².
[3] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.
[4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm².
(1) FR4 PCB, 4-layer copper; 1 cm²
(2) FR4 PCB, 4-layer copper; standard footprint
(3) FR4 PCB, single-sided copper; 1 cm²
(4) FR4 PCB, single-sided copper; standard footprint

Figure 1. Power derating curves

FR4 PCB, single-sided copper; standard footprint; single pulse;
$T_{\text{amb}} = 25 \, ^\circ\text{C}$

Figure 2. Safe operating area; junction to ambient; continuous and peak collector currents as a function of collector-emitter voltage
6 Thermal characteristics

Table 7. Thermal characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_{th(j-a)}$</td>
<td>thermal resistance from junction to ambient</td>
<td>in free air</td>
<td>[1]</td>
<td>-</td>
<td>-</td>
<td>358 K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[2]</td>
<td>-</td>
<td>-</td>
<td>218 K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[3]</td>
<td>-</td>
<td>-</td>
<td>209 K/W</td>
</tr>
<tr>
<td>$R_{th(j-sp)}$</td>
<td>thermal resistance from junction to solder point</td>
<td></td>
<td>[4]</td>
<td>-</td>
<td>-</td>
<td>157 K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>-</td>
<td>-</td>
<td>60 K/W</td>
</tr>
</tbody>
</table>

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².
[3] Device mounted on an FR4 PCB; 4-layer copper; tin-plated and standard footprint.
[4] Device mounted on an FR4 PCB; 4-layer copper; tin-plated; mounting pad for collector 1 cm².

Figure 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

Figure 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values
BC807K series
45 V, 500 mA PNP general-purpose transistors

FR4 PCB; 4-layer copper; tin plated and standard footprint

Figure 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

FR4 PCB; 4-layer copper; tin plated; mounting pad for collector 1 cm²

Figure 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values
## 7 Characteristics

### Table 8. Characteristics

*T<sub>amb</sub> = 25 °C unless otherwise specified.*

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>V&lt;sub&gt;(BR)CBO&lt;/sub&gt;</td>
<td>collector-base breakdown voltage</td>
<td>I&lt;sub&gt;C&lt;/sub&gt; = -100 µA; I&lt;sub&gt;E&lt;/sub&gt; = 0 A</td>
<td>-50</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>V&lt;sub&gt;(BR)CEO&lt;/sub&gt;</td>
<td>collector-emitter breakdown voltage</td>
<td>I&lt;sub&gt;C&lt;/sub&gt; = -10 mA; I&lt;sub&gt;B&lt;/sub&gt; = 0 A</td>
<td>-45</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>V&lt;sub&gt;(BR)EBO&lt;/sub&gt;</td>
<td>emitter-base breakdown voltage</td>
<td>I&lt;sub&gt;E&lt;/sub&gt; = -100 µA; I&lt;sub&gt;C&lt;/sub&gt; = 0 A</td>
<td>-5</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>I&lt;sub&gt;CBO&lt;/sub&gt;</td>
<td>collector-base cut-off current</td>
<td>V&lt;sub&gt;CB&lt;/sub&gt; = -25 V; I&lt;sub&gt;E&lt;/sub&gt; = 0 A</td>
<td>-</td>
<td>-</td>
<td>-100</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>V&lt;sub&gt;CB&lt;/sub&gt; = -25 V; I&lt;sub&gt;E&lt;/sub&gt; = 0 A; T&lt;sub&gt;j&lt;/sub&gt; = 150 °C</td>
<td>-</td>
<td>-</td>
<td>-5</td>
<td>µA</td>
</tr>
<tr>
<td>I&lt;sub&gt;EBO&lt;/sub&gt;</td>
<td>emitter-base cut-off current</td>
<td>V&lt;sub&gt;EB&lt;/sub&gt; = -5 V; I&lt;sub&gt;C&lt;/sub&gt; = 0 A</td>
<td>-</td>
<td>-</td>
<td>-100</td>
<td>nA</td>
</tr>
<tr>
<td>h&lt;sub&gt;FE&lt;/sub&gt;</td>
<td>DC current gain</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BC807K-16</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -1 V; I&lt;sub&gt;C&lt;/sub&gt; = -100 mA</td>
<td>[1]</td>
<td>100</td>
<td>-</td>
<td>250</td>
<td></td>
</tr>
<tr>
<td>BC807K-25</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -1 V; I&lt;sub&gt;C&lt;/sub&gt; = -100 mA</td>
<td>[1]</td>
<td>160</td>
<td>-</td>
<td>400</td>
<td></td>
</tr>
<tr>
<td>BC807K-40</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -1 V; I&lt;sub&gt;C&lt;/sub&gt; = -100 mA</td>
<td>[1]</td>
<td>250</td>
<td>-</td>
<td>600</td>
<td></td>
</tr>
<tr>
<td>BC807K-16, -25, -40</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -1 V; I&lt;sub&gt;C&lt;/sub&gt; = -500 mA</td>
<td>[1]</td>
<td>40</td>
<td>-</td>
<td>-</td>
<td></td>
</tr>
<tr>
<td>V&lt;sub&gt;CEsat&lt;/sub&gt;</td>
<td>collector-emitter saturation voltage</td>
<td>I&lt;sub&gt;C&lt;/sub&gt; = -500 mA; I&lt;sub&gt;B&lt;/sub&gt; = -50 mA</td>
<td>[1]</td>
<td>-</td>
<td>-</td>
<td>-700</td>
</tr>
<tr>
<td>V&lt;sub&gt;BEsat&lt;/sub&gt;</td>
<td>base-emitter saturation voltage</td>
<td>I&lt;sub&gt;C&lt;/sub&gt; = -500 mA; I&lt;sub&gt;B&lt;/sub&gt; = -50 mA</td>
<td>[1]</td>
<td>-</td>
<td>-</td>
<td>-1.2</td>
</tr>
<tr>
<td>V&lt;sub&gt;BE&lt;/sub&gt;</td>
<td>base-emitter voltage</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -1 V; I&lt;sub&gt;C&lt;/sub&gt; = -500 mA</td>
<td>[1]</td>
<td>-</td>
<td>-</td>
<td>-1.2</td>
</tr>
<tr>
<td>f&lt;sub&gt;T&lt;/sub&gt;</td>
<td>transition frequency</td>
<td>V&lt;sub&gt;CE&lt;/sub&gt; = -5 V; I&lt;sub&gt;C&lt;/sub&gt; = -10 mA; f = 100 MHz</td>
<td>80</td>
<td>-</td>
<td>-</td>
<td>MHz</td>
</tr>
<tr>
<td>C&lt;sub&gt;c&lt;/sub&gt;</td>
<td>collector capacitance</td>
<td>V&lt;sub&gt;CB&lt;/sub&gt; = -10 V; I&lt;sub&gt;E&lt;/sub&gt; = i&lt;sub&gt;e&lt;/sub&gt; = 0 A; f = 1 MHz</td>
<td>-</td>
<td>7</td>
<td>-</td>
<td>pF</td>
</tr>
<tr>
<td>C&lt;sub&gt;e&lt;/sub&gt;</td>
<td>emitter capacitance</td>
<td>V&lt;sub&gt;EB&lt;/sub&gt; = -0.5 V; I&lt;sub&gt;C&lt;/sub&gt; = i&lt;sub&gt;c&lt;/sub&gt; = 0 A; f = 1 MHz</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BC807K-16</td>
<td></td>
<td></td>
<td>-</td>
<td>50</td>
<td>-</td>
<td>pF</td>
</tr>
<tr>
<td>BC807K-25</td>
<td></td>
<td></td>
<td>-</td>
<td>45</td>
<td>-</td>
<td>pF</td>
</tr>
<tr>
<td>BC807K-40</td>
<td></td>
<td></td>
<td>-</td>
<td>37</td>
<td>-</td>
<td>pF</td>
</tr>
</tbody>
</table>

[1] pulsed; t<sub>p</sub> ≤ 300 µs; δ ≤ 0.02
Figure 7. BC807K-16: DC current gain as a function of collector current; typical values

<table>
<thead>
<tr>
<th>Condition</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CE}$</td>
<td>-1 V</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>150 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>125 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>100 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>85 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>25 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>-40 °C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>-55 °C</td>
</tr>
</tbody>
</table>

Figure 8. BC807K-16: DC current gain as a function of collector current; typical values

<table>
<thead>
<tr>
<th>Condition</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CE}$</td>
<td>-5 V</td>
</tr>
<tr>
<td>$V_{CE}$</td>
<td>-2 V</td>
</tr>
<tr>
<td>$V_{CE}$</td>
<td>-1 V</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>25 °C</td>
</tr>
</tbody>
</table>

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V_{CE} = -1 V
(1) T_{amb} = -55 °C
(2) T_{amb} = -40 °C
(3) T_{amb} = 25 °C
(4) T_{amb} = 85 °C
(5) T_{amb} = 100 °C
(6) T_{amb} = 125 °C
(7) T_{amb} = 150 °C

Figure 9. BC807K-16: Base-emitter voltage as a function of collector current; typical values

T_{amb} = 25 °C
(1) V_{CE} = -1 V
(2) V_{CE} = -2 V
(3) V_{CE} = -5 V

Figure 10. BC807K-16: Base-emitter voltage as a function of collector current; typical values
**BC807K series**

45 V, 500 mA PNP general-purpose transistors

---

Figure 11. BC807K-16: Base-emitter saturation voltage as a function of collector current; typical values

Figure 12. BC807K-16: Base-emitter saturation voltage as a function of collector current; typical values

Figure 13. BC807K-16: Collector-emitter saturation voltage as a function of collector current; typical values

Figure 14. BC807K-16: Collector-emitter saturation voltage as a function of collector current; typical values
**Nexperia**

**BC807K series**

45 V, 500 mA PNP general-purpose transistors

---

**Figure 15. BC807K-16: Collector current as a function of collector-emitter voltage; typical values**

\[ I_C (A) \]

\[ V_{CE} (V) \]

\[ I_B (mA) = -15.0 \]

\[ -1.0 \]

\[ -1.5 \]

\[ -2.0 \]

\[ -2.5 \]

\[ -3.0 \]

\[ -3.5 \]

\[ -4.0 \]

\[ -4.5 \]

\[ -5.0 \]

\[ 0 \]

\[ 0.2 \]

\[ 0.4 \]

\[ 0.6 \]

\[ 0.8 \]

\[ 1.0 \]

\[ 1.5 \]

\[ 2.0 \]

\[ 2.5 \]

\[ 3.0 \]

\[ 3.5 \]

\[ 4.0 \]

\[ 4.5 \]

\[ 5.0 \]

\[ 0 \]

\[ -5 \]

\[ -10 \]

\[ -15 \]

\[ -20 \]

\[ -25 \]

\[ -30 \]

\[ -35 \]

\[ -40 \]

\[ -45 \]

\[ -50 \]

\[ T_{amb} = 25 \, ^\circ C \]

---

**Figure 16. BC807K-16: Collector capacitance as a function of collector-base voltage; typical values**

\[ C_C (pF) \]

\[ V_{CB} (V) \]

\[ f = 1 \, MHz; \, T_{amb} = 25 \, ^\circ C \]

---

**Figure 17. BC807K-16: Emitter capacitance as a function of emitter-base voltage; typical values**

\[ C_E (pF) \]

\[ V_{EB} (V) \]

\[ f = 1 \, MHz; \, T_{amb} = 25 \, ^\circ C \]

---

**Figure 18. BC807K-16: Transition frequency as a function of collector current voltage; typical values**

\[ f_T (MHz) \]

\[ I_C (mA) \]

\[ I_C (mA) \]

\[ V_{CE} = -5 \, V \]

\[ (1) \]

\[ V_{CE} = -1 \, V \]

\[ (2) \]

\[ f = 100 \, MHz; \, T_{amb} = 25 \, ^\circ C \]

---

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Product data sheet

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Figure 19. BC807K-25: DC current gain as a function of collector current; typical values

V_{CE} = -1 V
1) T_{amb} = 150 °C
2) T_{amb} = 125 °C
3) T_{amb} = 100 °C
4) T_{amb} = 85 °C
5) T_{amb} = 25 °C
6) T_{amb} = -40 °C
7) T_{amb} = -55 °C

T_{amb} = 25 °C
1) V_{CE} = -5 V
2) V_{CE} = -2 V
3) V_{CE} = -1 V

Figure 20. BC807K-25: DC current gain as a function of collector current; typical values
Figure 21. BC807K-25: Base-emitter voltage as a function of collector current; typical values

\[ V_{CE} = -1 \text{ V} \]
1. \( T_{amb} = -55 \text{ °C} \)
2. \( T_{amb} = -40 \text{ °C} \)
3. \( T_{amb} = 25 \text{ °C} \)
4. \( T_{amb} = 85 \text{ °C} \)
5. \( T_{amb} = 100 \text{ °C} \)
6. \( T_{amb} = 125 \text{ °C} \)
7. \( T_{amb} = 150 \text{ °C} \)

Figure 22. BC807K-25: Base-emitter voltage as a function of collector current; typical values

\[ T_{amb} = 25 \text{ °C} \]
1. \( V_{CE} = -1 \text{ V} \)
2. \( V_{CE} = -2 \text{ V} \)
3. \( V_{CE} = -5 \text{ V} \)
**Nexperia**

**BC807K series**

45 V, 500 mA PNP general-purpose transistors

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**Figure 23. BC807K-25: Base-emitter saturation voltage as a function of collector current; typical values**

- $V_{BE_{Sat}}$ (V) vs. $I_C$ (mA)
  - $I_C/I_B = 10$
  - $T_{amb}$ values: -55 °C, -40 °C, 25 °C, 85 °C, 100 °C, 125 °C, 150 °C

**Figure 24. BC807K-25: Base-emitter saturation voltage as a function of collector current; typical values**

- $V_{BE_{Sat}}$ (V) vs. $I_C$ (mA)
  - $I_C/I_B$ values: 10, 20, 50, 100

---

**Figure 25. BC807K-25: Collector-emitter saturation voltage as a function of collector current; typical values**

- $V_{CE_{Sat}}$ (V) vs. $I_C$ (mA)
  - $I_C/I_B = 10$
  - $T_{amb}$ values: -40 °C, 25 °C, 85 °C, 150 °C

**Figure 26. BC807K-25: Collector-emitter saturation voltage as a function of collector current; typical values**

- $V_{CE_{Sat}}$ (V) vs. $I_C$ (mA)
  - $I_C/I_B$ values: 10, 20, 50, 100
T_{amb} = 25 °C
Figure 27. BC807K-25: Collector current as a function of collector-emitter voltage; typical values

f = 1 MHz; T_{amb} = 25 °C
Figure 28. BC807K-25: Collector capacitance as a function of collector-base voltage; typical values

f = 1 MHz; T_{amb} = 25 °C
Figure 29. BC807K-25: Emitter capacitance as a function of emitter-base voltage; typical values

f = 100 MHz; T_{amb} = 25 °C
(1) V_{CE} = -5 V
(2) V_{CE} = -1 V
Figure 30. BC807K-25: Transition frequency as a function of collector current voltage; typical values
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V_{CE} = -1 V
(1) T_{amb} = 150 °C
(2) T_{amb} = 125 °C
(3) T_{amb} = 100 °C
(4) T_{amb} = 85 °C
(5) T_{amb} = 25 °C
(6) T_{amb} = -40 °C
(7) T_{amb} = -55 °C

T_{amb} = 25 °C
(1) V_{CE} = -5 V
(2) V_{CE} = -2 V
(3) V_{CE} = -1 V

Figure 31. BC807K-40: DC current gain as a function of collector current; typical values

Figure 32. BC807K-40: DC current gain as a function of collector current; typical values
V<sub>CE</sub> = -1 V
(1) T<sub>amb</sub> = -55 °C
(2) T<sub>amb</sub> = -40 °C
(3) T<sub>amb</sub> = 25 °C
(4) T<sub>amb</sub> = 85 °C
(5) T<sub>amb</sub> = 100 °C
(6) T<sub>amb</sub> = 125 °C
(7) T<sub>amb</sub> = 150 °C

T<sub>amb</sub> = 25 °C
(1) V<sub>CE</sub> = -1 V
(2) V<sub>CE</sub> = -2 V
(3) V<sub>CE</sub> = -5 V

Figure 33. BC807K-40: Base-emitter voltage as a function of collector current; typical values

Figure 34. BC807K-40: Base-emitter voltage as a function of collector current; typical values
**Figure 35. BC807K-40: Base-emitter saturation voltage as a function of collector current; typical values**

- $V_{BE_{sat}}$ ($V$) vs. $I_C$ (mA)
- $I_C/I_B = 10$
- (1) $T_{amb} = -55 \, ^\circ C$
- (2) $T_{amb} = -40 \, ^\circ C$
- (3) $T_{amb} = 25 \, ^\circ C$
- (4) $T_{amb} = 85 \, ^\circ C$
- (5) $T_{amb} = 100 \, ^\circ C$
- (6) $T_{amb} = 125 \, ^\circ C$
- (7) $T_{amb} = 150 \, ^\circ C$

**Figure 36. BC807K-40: Base-emitter saturation voltage as a function of collector current; typical values**

- $T_{amb} = 25 \, ^\circ C$
- (1) $I_C/I_B = 10$
- (2) $I_C/I_B = 20$
- (3) $I_C/I_B = 50$
- (4) $I_C/I_B = 100$

**Figure 37. BC807K-40: Collector-emitter saturation voltage as a function of collector current; typical values**

- $V_{CE_{sat}}$ ($V$) vs. $I_C$ (mA)
- $I_C/I_B = 10$
- (1) $T_{amb} = 150 \, ^\circ C$
- (2) $T_{amb} = 85 \, ^\circ C$
- (3) $T_{amb} = 25 \, ^\circ C$
- (4) $T_{amb} = -40 \, ^\circ C$

**Figure 38. BC807K-40: Collector-emitter saturation voltage as a function of collector current; typical values**

- $T_{amb} = 25 \, ^\circ C$
- (1) $I_C/I_B = 100$
- (2) $I_C/I_B = 50$
- (3) $I_C/I_B = 20$
- (4) $I_C/I_B = 10$
8 Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.
9 Package outline

Table 9. Package outline

Figure 43. Package outline SOT23 (TO-236)

10 Soldering

Table 10. Soldering

Figure 44. Reflow soldering footprint for SOT23 (TO-236AB)
11 Revision history

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12 Legal information

12.1 Data sheet status

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[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL: http://www.nexperia.com.

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